



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

September 16, 2026

IGI Report Number

DESCRIPTION

SHAPE AND CUTTING STYLE

MEASUREMENTS

GRADING RESULTS

CARAT WEIGHT

COLOR GRADE

CLARITY GRADE

ADDITIONAL GRADING INFORMATION

POLISH

SYMMETRY

FLUORESCENCE

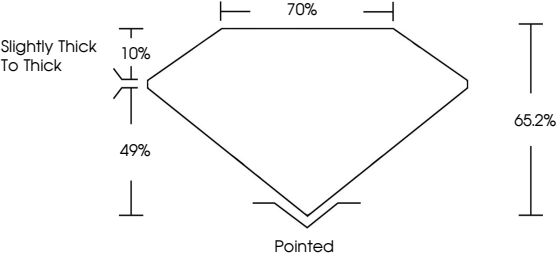
INSCRIPTION(S)

COMMENTS: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa

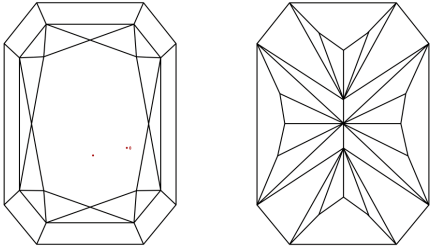
LG836693470

Report verification at igi.org

PROPORTIONS



CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

CLARITY

FL

IF

VVS¹⁻²

VS¹⁻²

SI¹⁻²

I¹⁻³

Flawless

Internally Flawless

Very Very Slightly Included

Very Slightly Included

Slightly Included

Included



Sample Image Used

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IGI Report No LG836693470

CUT CORNERED RECT. MODIFIED BRILLIANT

13.62 X 8.70 X 5.67 MM

5.82 CARATS

E

VS 1

65.2%

70%

Slightly Thick To Thick

Pointed

EXCELLENT

VERY GOOD

NONE

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